## NSN 5961-01-216-2051

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Inclosure Material:
Metal
Overall Length:
0.520 inches
Overall Diameter:
1.250 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-36
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage, dc and 80.0 emitter to base voltage, dc and 75.0 collector to emitter voltage, dc
Current Rating Per Characteristic:
3.00 milliamperes source cutoff current
Power Rating Per Characteristic:
170.0 watts small-signal input power, common-collector
Transfer Ratio:
50.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnp
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

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